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Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier



Cathode O Anode

DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS			
I _{F(AV)}	3.0 A		
V _{RRM}	200 V		
I _{FSM}	60 A		
V_F at I_F = 3.0 A	0.70 V		
T _J max.	175 °C		
Package	SMP (DO-220AA)		
Circuit configuration	Single		

FEATURES

- Low profile package
- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
 FREE
- AEC-Q101 qualified available - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL		UNIT	
Device marking code		V3D		
Maximum repetitive peak reverse voltage	V _{RRM}	V _{RRM} 200		
Maximum DC forward current	I _{F(AV)} ⁽¹⁾	3	А	
	I _{F(AV)} ⁽²⁾	1.7	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	60	A	
Operating junction and storage temperature range	T _J ⁽³⁾	-40 to +175	°C	
Operating junction and storage temperature range	T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ Mounted on 10 mm x 10 mm PCB pad area

⁽²⁾ Free air, mounted on recommended copper pad area

⁽³⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$





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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 1.5 A	- T _A = 25 °C	- V _F (1)	0.78	-	V
	$I_F = 3 A$			0.85	0.94	
	I _F = 1.5 A	- T _A = 125 °C		0.62	-	
	I _F = 3 A			0.70	0.78	
Reverse current	V 160 V	T _A = 25 °C	I _R (2)	0.001	-	mA mA
	v _R = 100 v	T _A = 25 °C T _A = 125 °C		0.3	-	
	V - 200 V	T _A = 25 °C T _A = 125 °C		-	0.05	
	v _R = 200 v	T _A = 125 °C		0.7	3.0	
Typical junction capacitance	4.0 V, 1 M⊦	4.0 V, 1 MHz		120	-	pF

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)				
PARAMETER	SYMBOL	V3P22	UNIT	
Typical thermal resistance	R _{0JA} ⁽¹⁾⁽²⁾	125	°C/W	
	R _{0JM} ⁽³⁾	15	0/10	

Notes

 $^{(1)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$

 $^{(2)}$ Free air, mounted on recommended copper pad area; thermal resistance R_{0JA} - junction-to-ambient

 $^{(3)}$ Mounted on 10 mm x 10 mm aluminum PCB; thermal resistance $R_{\theta JM}$ - junction-to-mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V3P22-M3/H	0.024	Н	3000	7" diameter plastic tape and reel		
V3P22-M3/I	0.024	I	10 000	13" diameter plastic tape and reel		
V3P22HM3/H ⁽¹⁾	0.024	Н	3000	7" diameter plastic tape and reel		
V3P22HM3/I ⁽¹⁾	0.024	I	10 000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

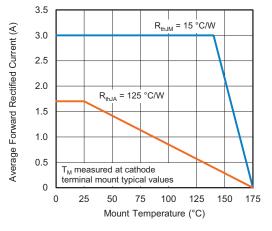


Fig. 1 - Maximum Forward Current Derating Curve

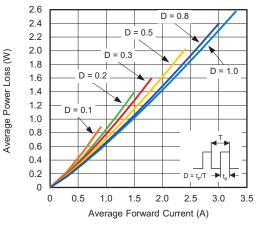


Fig. 2 - Forward Power Loss Characteristics

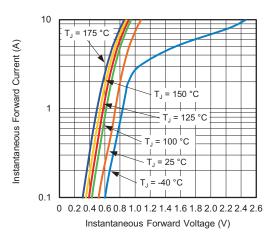


Fig. 3 - Typical Instantaneous Forward Characteristics

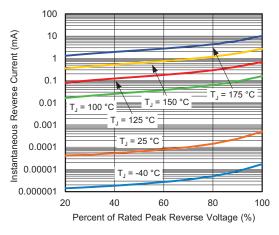


Fig. 4 - Typical Reverse Characteristics

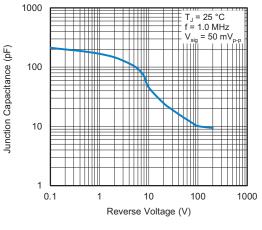


Fig. 5 - Typical Junction Capacitance

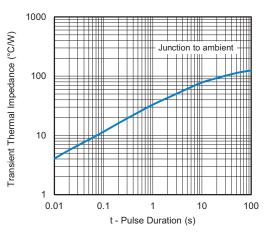


Fig. 6 - Typical Transient Thermal Impedance

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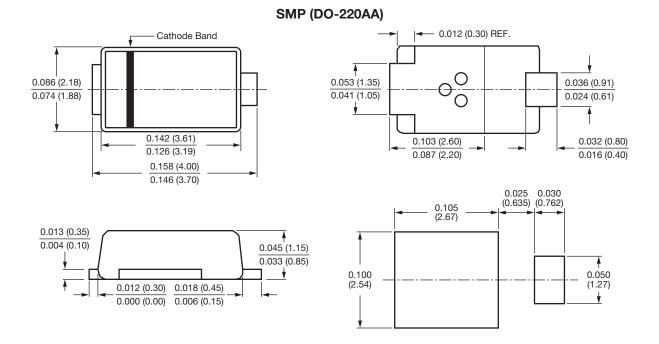
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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